

CONVENTION

AUSTRALIA

Patents Act 1990

655832

REQUEST FOR A STANDARD PATENT

AND NOTICE OF ENTITLEMENT

The Applicant identified below requests the grant of a patent to the nominated person identified below for an invention described in the accompanying standard complete patent specification.

[70,71]Applicant and Nominated Person:

Corning Incorporated

Houghton Park, Corning, New York, UNITED STATES OF AMERICA

[54]Invention Title:

METHOD OF MAKING FUSED SILICA

[72]Actual Inventors:

Carlton Maurice Truesdale

Jeffery Lynn Blackwell

Michael Sean Dobbins

Robert Ernest McLay

[74]Address for Service:

PHILLIPS ORMONDE & FITZPATRICK  
367 Collins Street  
Melbourne 3000 AUSTRALIA

[31,33,32]

Details of basic application(s):-

750,561

UNITED STATES OF AMERICA

US

26 August 1991

Applicant states the following:

1. The nominated person is the assignee of the actual inventor(s)
2. The nominated person is  
~~the applicant~~  
- the assignee of the applicant  
~~authorised to make this application by the applicant~~  
of the basic application.
3. The basic application(s) was/were the first made in a convention country in respect of the invention.

The nominated person is not an opponent or eligible person described in Section 33-36 of the Act.

24 August 1992

Corning Incorporated  
By PHILLIPS ORMONDE & FITZPATRICK  
Patent Attorneys  
By

Our Ref : 282491

*David B Fitzpatrick*

5999q



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**(12) PATENT ABRIDGMENT**      **(11) Document No. AU-B-21260/92**  
**(19) AUSTRALIAN PATENT OFFICE**      **(10) Acceptance No. 655832**

- (54) Title  
**METHOD OF MAKING FUSED SILICA**
- International Patent Classification(s)  
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- (71) Applicant(s)  
**CORNING INCORPORATED**
- (72) Inventor(s)  
**CARLTON MAURICE TRUESDALE; JEFFERY LYNN BLACKWELL; MICHAEL SEAN DOBBINS;  
ROBERT ERNEST MCLAY**
- (74) Attorney or Agent  
**PHILLIPS ORMONDE & FITZPATRICK , 367 Collins Street, MELBOURNE VIC 3000**
- (56) Prior Art Documents  
**US 4501602**  
**US 4472510**
- (57) Claim

1. A method for making a virtually non-porous body of high purity fused silica glass which includes the steps of:

(a) producing a gas stream of a halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to SiO<sub>2</sub>;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused SiO<sub>2</sub>;

(c) depositing said amorphous particles onto a support; and

(d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a virtually nonporous body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(11) AU-9-21260/92  
(10) 655832

-2-

(2) a boiling point no higher than 350°C; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards;

wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

9. A method for making a non-porous body of high purity silica doped with  $\text{P}_2\text{O}_5$  and/or at least one metal oxide selected from the groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table including the steps of:

(a) producing a gas stream containing a vaporizable, halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$  and a compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{P}_2\text{O}_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused

$\text{SiO}_2$  doped with  $\text{P}_2\text{O}_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

(c) depositing said amorphous particles onto a support; and

(d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a non-porous body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(11) AU-B-21260/92  
(10) 655832

-3-

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than 350°C;  
and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

19. A method for making optical waveguide fibers of high purity fused silica through the outside vapor deposition process including the steps of:

(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to SiO<sub>2</sub>;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused SiO<sub>2</sub>;

(c) depositing said amorphous particles onto a mandrel;

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; and

(e) drawing optical waveguide fiber from said body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than 350°C;  
and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said

(11) AU-B-21260/92  
(10) 655832

-4-

organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

27. A method for making optical waveguide fibers of high purity fused silica doped with  $P_2O_5$  and/or at least one metal oxide selected from the groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table through the outside vapor deposition process including the steps of:

(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $SiO_2$  and a compound in vapor form capable of being converted through thermal decomposition with through oxidation or flame hydrolysis to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $SiO_2$  doped with  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

(c) depositing said amorphous particles onto a mandrel;

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; and

(e) drawing optical waveguide fiber from said body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than  $350^{\circ}C$ ;

and

(3) which, upon pyrolysis and/or hydrolysis,

(11) AU-B-21260/92

-5-

(10) 655832

will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

37. A method for making high purity fused silica including the steps of:

(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$ ;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $\text{SiO}_2$ ;

(c) depositing said amorphous particles onto a mandrel; and

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than  $350^\circ\text{C}$ ;

and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

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Patents Act

655832

COMPLETE SPECIFICATION  
(ORIGINAL)

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Lodged: \_\_\_\_\_

Complete Specification Lodged: \_\_\_\_\_  
Accepted: \_\_\_\_\_  
Published: \_\_\_\_\_

Priority \_\_\_\_\_

Related Art: \_\_\_\_\_

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Name of Applicant:

Corning Incorporated

Actual Inventor(s):

Carlton Maurice Truesdale  
Jeffery Lynn Blackwell  
Michael Sean Dobbins  
Robert Ernest McLay

Address for Service:

PHILLIPS ORMONDE & FITZPATRICK  
Patent and Trade Mark Attorneys  
367 Collins Street  
Melbourne 3000 AUSTRALIA

Invention Title:

**METHOD OF MAKING FUSED SILICA**

Our Ref : 282491  
POF Code: 1602/1602

The following statement is a full description of this invention, including the best method of performing it known to applicant(s):

METHOD OF MAKING FUSED SILICA

Related Application

5 United States Patent Application Serial No. filed  
concurrently herewith by J.L. Blackwell et al. under the  
title METHOD OF MAKING TITANIA-DOPED FUSED SILICA, is  
directed to the production of high purity fused silica  
glass doped with titanium wherein fused silica glass is  
10 doped through the use of a halide-free, titanium  
containing compound in vapour form capable of being  
converted through thermal decomposition with oxidation or  
flame hydrolysis to  $TiO_2$  selected from the group  
consisting of titanium, isopropoxide, titanium ethoxide,  
15 titanium-2-ethylhexyloxyde, titanium cyclopentyloxyde, a  
~~titanium amide, and mixtures thereof.~~

Background

20 Various processes are known in the art that involve  
the production of metal oxides from vaporous reactants.  
The most basic requirements of such processes necessitate  
a feedstock solution, a means of generating and  
transporting vapors of the feedstock solution (hereafter  
25 called vaporous reactants) and an oxidant to a reaction  
site, and

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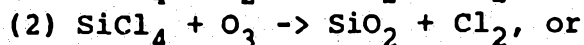
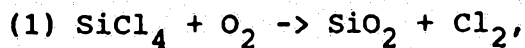




a means of catalyzing oxidation and combustion coincidentally, producing finely divided, spherical aggregates, called soot. This soot may be collected in any number of ways, ranging from a collection chamber to a rotating mandrel, and simultaneously or subsequently heat treated to form a non-porous, transparent, high purity glass article. The means for executing these reactions is usually a specialized piece of equipment with a unique arrangement of nozzles and burners.

Much of the initial research that led to the development, and thus patent protection, of a plethora of such processes focused on the production of fused silica. Selection of the appropriate feedstock was found to be as important in the production of high purity fused silica as the equipment used in its production. Consequently, a material was identified that could generate the needed vapor pressure of 200 - 300 mm at temperatures below 100°C; the high vapor pressure of silicon tetrachloride ( $\text{SiCl}_4$ ) isolated it as a convenient vapor source for soot generation, thus launching the discovery and use of a series of similar chloride-based feedstocks. This factor, more than any other, is responsible for the presently accepted use of  $\text{SiCl}_4$ ,  $\text{GeCl}_4$ ,  $\text{POCl}_3$ , and  $\text{BCl}_3$  as vapor sources, even though these materials have certain chemically undesirable properties.

Silicon, germanium, zirconium, and titanium are metals often used in chloride form as vaporous reactants for forming high purity metal oxide glasses. However,  $\text{SiCl}_4$  has been the industry standard among metal-source vaporous reactants used over the years for the production of high purity silica glasses. As disclosed in U.S. Patent 3,698,936, one of several reactions may be employed to produce high purity fused silica via oxidation of  $\text{SiCl}_4$ ; namely:



(3)  $\text{SiCl}_4 + \text{H}_2\text{O} \rightarrow \text{SiO}_2 + \text{HCl}$ , whereby burners or jet assemblies are utilized in feeding the reactant gases and vapors to a reaction space. There are inherent economic disadvantages to each of these reactions.

5        These reactions, which oxidize  $\text{SiCl}_4$  through pyrolysis and hydrolysis, have the disadvantage of producing a very strong acid by-product. While the first two reactions occur theoretically, it is likely that an auxiliary fuel is needed to achieve pyrolytic temperature, thus leading to hydrolysis of the silicon tetrachloride and formation of hydrochloric acid (HCl). Such a by-product is not only a detriment to many deposition substrates and the reaction equipment, but also has to be treated before being released into the environment. Such abatement systems have proven to be very expensive due to  
10        down-time, loss, and maintenance of equipment caused by the corrosiveness of HCl.  
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      The first reaction, which utilizes oxygen as it occurs naturally, requires elevated reaction temperatures which, generally, are difficult to maintain without using specialized equipment. The second reaction requires  
20        ozone, an unstable form of molecular oxygen that not only warrants special handling, but also must be manufactured on site due to a lack of commercial availability. Notwithstanding the handling and disposal of the HCl by-product necessitated by the hydrolysis and pyrolysis of  $\text{SiCl}_4$ ,  
25        the third reaction, also hydrolysis of  $\text{SiCl}_4$ , tends to be the preferred commercial method of producing fused silica for economic reasons.

      Though hydrolysis of  $\text{SiCl}_4$  has been the preference of industry for producing high purity fused silica over the  
30        years, the enhanced global sensitivity to environmental protection has led to more strict government regulation of point source emissions, prompting a search for less environmentally pernicious feedstocks. In new point  
35        source emission regulations, HCl, the byproduct of

hydrolyzing  $\text{SiCl}_4$ , as well as many particulate pollutants, has to be cleansed from exhaust gases prior to being released into the atmosphere. The economic consequences of meeting these regulations have made commercial production of fused silica by downstream removal of HCl and other metal oxides from chloride-based feedstocks less attractive to industry.

As an alternative, high purity fused quartz or silica may also be produced by thermal decomposition and oxidation of silane, a compound that requires taking safety measures in handling due to the violent reaction caused when air is introduced into a closed container of silane. Silane is commonly reacted with carbon dioxide, nitrous oxide, oxygen, or water to produce a high purity material that is useful in producing, among other things, semiconductor devices, while emitting a host of by-products such as carbon monoxide, hydrogen, and nitrogen. However, silane has proven to be much too expensive and reactive to be considered for commercial use except possibly for extremely high purity applications.

The novelty of the invention described herein lies in the replacement of  $\text{SiCl}_4$  in vapor deposition processes with a chloride-free, silica-source compound, thus greatly reducing, if not eliminating, the production of HCl. The advantages of operating under a chloride-free system include: reduced pollution abatement requirements and reduced equipment losses and maintenance due to the corrosive nature of HCl.

The teachings of the instant invention are easily adapted to known methods of producing high purity fused silica by flame pyrolysis or hydrolysis, such as those disclosed in the early patents by Nordberg (U.S. Patent 2,239,551) in 1941 and Hyde (U.S. Patent 2,272,342) in 1942. It is anticipated that this process alteration may be adapted to a variety of deposition/collection techniques as well. Therefore, it is an object of this

invention to provide an improved method of making high purity fused silica by utilizing alternative silicon-source compounds, thus reducing, if not eliminating, one or more of the disadvantages of the prior art.

5 While it is recognized that the primary application of the instant invention relates to the production of fused silica, the technology applied herein is generally applicable in instances where a high purity metal oxide glass is desired.

10 It is a further object of this invention to provide an improved method of making high purity metal oxide glasses through the use of alternative metal oxide source compounds, thereby reducing or overcoming one or more problems of the prior art.

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#### Summary of the Invention

According to the present invention, there is provided a method for making a virtually non-porous body of high purity fused silica glass which includes the steps of:

20 (a) producing a gas stream of a halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$ ;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $\text{SiO}_2$ ;

25 (c) depositing said amorphous particles onto a support; and

30 (d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a virtually nonporous body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

- 35
- (1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;
  - (2) a boiling point no higher than  $350^\circ\text{C}$ ; and
  - (3) which, upon pyrolysis and/or hydrolysis, will



produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards;

5 wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

10 The present invention also provides a method for making a non-porous body of high purity silica doped with  $\text{P}_2\text{O}_5$  and /or at least one metal oxide selected from the groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table including the steps of:

15 (a) producing a gas stream containing a vaporizable, halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$  and a compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{P}_2\text{O}_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

20 (b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $\text{SiO}_2$ ; doped with  $\text{P}_2\text{O}_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

30 (c) depositing said amorphous particles onto a support; and

(d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a nonporous body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

35 (1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;



(2) a boiling point no higher than 350°C; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards;

wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

The present invention further provides a method for making optical waveguide fibers of high purity fused silica through the outside vapor deposition process including the steps of:

(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to SiO<sub>2</sub>;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused SiO<sub>2</sub>;

(c) depositing said amorphous particles onto a mandrel;

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; and

(e) drawing optical waveguide fiber from said body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than 350°C; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards;

wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen



compounds, organosilicon-nitrogen compounds,  
siloxasilazanes, and mixtures thereof.

Moreover, the present invention provides a method  
for making optical waveguide fibers of high purity fused  
silica doped with  $P_2O_5$  and/or at least one metal oxide  
5 selected from the groups IA, IB, IIA, IIB, IIIA, IIIB,  
IVA, IVB, VA, and the rare earth series of the Periodic  
Table through the outside vapor deposition process  
including the steps of:

10 (a) producing a gas stream containing a silicon-  
containing compound in vapor form capable of being  
converted through thermal decomposition with oxidation or  
flame hydrolysis to  $SiO_2$  and a compound in vapor form  
capable of being converted thermal decompositon with  
15 through oxidation or flame hydrolysis to  $P_2O_5$  and/or  
at least one metal oxide selected from the Groups IA, IB,  
IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth  
series of the Periodic Table;

20 (b) passing said gas stream into the flame of a  
combustion burner to form amorphous particles of fused  
 $SiO_2$  doped with  $P_2O_5$  and/or at least one metal oxide  
selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB,  
IVA, IVB, VA, and the rare earth series of the Periodic  
Table;

25 (c) depositing said amorphous particles onto a  
mandrel;

(d) consolidating said deposit of amorphous  
particles into a non-porous, transparent glass body; and

30 (e) drawing optical waveguide fiber from said  
body; wherein a halide-free, organosilicon-R compound in  
vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no  
higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than  $350^\circ C$ ; and

35 (3) which, upon pyrolysis and/or hydrolysis, will  
produce decomposition products beside  $SiO_2$  which are  
deemed to be environmentally safe or the emissions are  
below acceptable governmental standards;



wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

5 The present invention additionally provides a method for making high purity fused silica including the steps of:

(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or  
10 flame hydrolysis to  $\text{SiO}_2$ ;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  
 $\text{SiO}_2$ ;

(c) depositing said amorphous particles onto a  
15 mandrel; and

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties;

20 (1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than  $350^\circ\text{C}$ ; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are  
25 deemed to be environmentally safe or the emissions are below acceptable governmental standards;

wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds,  
30 siloxasilazanes, and mixtures thereof.

In like manner to the disclosure of US Patent No. 5,043,002 the instant invention utilizes halide-free, silicon-containing compounds as a replacement for the  
35 halide-based source feedstocks that are often oxidized by flame hydrolysis or pyrolysis, to produce transparent, high-purity silica glass articles. The production of





fused silica glass through the use of pyrolyzable and/or hydrolyzable halide-free, silicon-containing compounds as the feedstock components results in carbon dioxide and water as the by-products.

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In US Patent No. 5,043,002 we described and claimed polymethylsiloxanes as halide-free, silicon-containing compounds for use as replacements for halide-based source feedstocks, with polymethylcyclsiloxanes being the preferred members of that group of compounds. Thus, octamethylcyclotetrasiloxane, decamethylcyclopentasiloxane, and hexamethylcyclotrisiloxane were disclosed as being especially suitable as halide-free feestocks.

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Further laboratory work has demonstrated that operable halide-free, silicon-containing feedstocks need not be limited to the polymethylsiloxanes. That is, we have found that organosilicon materials satisfying the following three criteria can be suitably utilized as substitutes for halide-containing compounds:

(1) an operable organosilicon-R compound (R is an element of the Periodic Table) will have a Si-R bond dissociation energy that is no higher than that of the Si-O bond;

(2) an operable organosilicon-R compound will exhibit a significant vapor pressure at temperatures below 250°C and a boiling point no higher than 350°C; and, in the interest of safety,

(3) an operable organosilicon-R compound will, upon pyrolysis and/or hydrolysis, yield decomposition products besides SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards.

That fundamental discovery resulted from our finding of a large number of halide-free, silicon-source compounds exhibiting a variety of bonding arrangements to the silicon atom that have proven to be useful as substitutes for halide-based materials. Three groups of compounds which have been found to be especially useful are categorized below according to the bonding arrangement in the basic structure:

(1) organosilicon-oxygen compounds, having a basic Si-O-Si structure, in particular linear siloxanes wherein an oxygen atom and a single element or group of elements, such as a methyl group, is bonded to the silicon atom;

(2) organosilicon-nitrogen compounds, having a basic Si-N-Si structure, such as aminosilanes, linear silazanes, and cyclosilazanes, wherein a nitrogen atom and a single element or group of elements are bonded to the silicon atom; and

(3) siloxasilazanes, having a basic Si-N-Si-O-Si structure, wherein a nitrogen atom and an oxygen atom are bonded to the silicon atom.

5 These compounds have a significant vapor pressure when heated above 150°C. The prior art discloses halide-containing silanes as sources for producing silica (e.g.,  $\text{Si-R}_m\text{Cl}_{2-m}$ , where R is an organic group). Our experiments indicate that the presence of a halide is not necessary; indeed, organosilicon-R compounds free from halides produce silica having very high purity. Also, it must be  
10 recognized that, although the three groups of organosilicon-R compounds cited above as preferred embodiments of our invention disclose specific bonding arrangements in relation to the Si atom, these compounds are actually but a subset of a larger group of organosilicon-R  
15 compounds. Stated in another way, to be operable as a suitable feedstock, the halide-free, organosilicon-R compound need only to satisfy the three criteria outlined above.

20 Octamethyltrisiloxane is illustrative of an operable linear siloxane. Tris (trimethylsilyl) ketenimine, nonamethyltrisilazane, and octamethylcyclotetrasilazane are illustrative of an operable aminosilane, a linear silazane, and a cyclosilazane, respectively, and  
25 hexamethylcyclotrisiloxazane is illustrative of an operable siloxasilazane. The representative compounds in each of these classes of compounds comprise the preferred embodiment of each respective class.

Methyltrimethoxysilane (MTMS) has also been shown to be operable as a feedstock for producing fused silica of  
30 high purity, but it is very expensive and is more difficult to control in the combustion flame. Hence, whereas MTMS can conceivably be used as a substitute for the halide-based, silicon-containing compounds, its properties militate against our use thereof.

It will be appreciated that, similarly to the current commercial processes for doping fused  $\text{SiO}_2$  articles produced via the thermal decomposition with oxidation or hydrolysis of  $\text{SiCl}_4$  with various metals in order to modify the chemical and/or physical properties thereof, the fused  $\text{SiO}_2$  articles prepared in accordance with the present invention can likewise be doped with metals. For example, fused silica articles have been doped commercially with  $\text{Al}_2\text{O}_3$ ,  $\text{B}_2\text{O}_3$ ,  $\text{GeO}_2$ ,  $\text{P}_2\text{O}_5$ , and  $\text{TiO}_2$  utilizing halide-containing compounds of aluminum, boron, germanium, phosphorous, and titanium, respectively. Like dopants can be utilized in the present inventive process but would, of course, provide a source of halide emissions. Consequently, to eliminate point source emissions of halides, organometallic compounds of the dopant metals will be employed. For example, isopropyl titanate and titanium ethoxide can be used as sources of titanium and methyl borate can furnish the dopant source of boron.

Further examples of operable organometallic dopants are found in U.S. Patent No. 4,501,602 (Miller et al.). That patent describes the production of glass/ceramic articles via a vapor phase oxidation process wherein  $\beta$ -diketonate complexes selected from Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, and IVB, and the rare earth series of the Periodic Table are vaporized, the vapor is transported to an oxidation site, such as a burner or a hot plasma zone which is adjacent to a deposition substrate or within a deposition tube, and oxidized in the vapor phase to form particulate metal oxide soot.  $\beta$ -diketonate complexes are also available of metals in Group VA of the Periodic Table, notably vanadium and tantalum. Accordingly, the use of  $\beta$ -diketonate complexes provides a vaporizable source for a wide variety of dopant metals. In summary, our invention comprehends doping of fused  $\text{SiO}_2$  articles with  $\text{P}_2\text{O}_5$  and/or at least one metal oxide

selected from Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table.

Prior Art

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A plethora of patents have issued that describe the production of high purity metal oxides, and particularly fused silica, from a chloride-based feedstock encompassed in or feeding into a specialized piece of equipment. Such equipment has featured a number of burner arrangements and feedstock delivery systems, all based on the oxidation of a metal chloride through flame hydrolysis or pyrolysis. Illustrative of this fact is U.S. Patent 4,491,604 (Lesk et al.) wherein trichlorosilane, dichlorosilane, and silicon tetrachloride are flame hydrolyzed to form soot, and U.S. Patent 3,666,414 (Bayer) wherein silicon halides, such as silicon chloroform, are flame hydrolyzed. In similar processes, U.S. Patents 3,486,913 (Zirngibl) and 2,269,059 (McLachlan) teach of oxidation of halides: volatilized inorganic halide components such as  $TiCl_4$ ,  $CrCl_3$ ,  $CrO_2Cl_2$ ,  $SiCl_4$ ,  $AlCl_3$ ,  $ZrCl_4$ ,  $FeCl_2$ ,  $FeCl_3$ ,  $ZnCl_2$ , or  $SnCl_4$  oxidized with air, steam, or oxygen are employed in '913; while silicon halides, ethyl silicate, methyl borate,  $TiCl_4$ ,  $AlCl_3$ , and  $ZrCl_4$  are employed in '059. None of the compounds cited in these references coincides with the halide-free, silicon-containing compounds of the instant invention, however.

U.S. Patent 3,416,890 (Best et al.) discloses a process for preparing finely-divided metal or metalloid oxides by the decomposition of a metal or metalloid perhalide in a flame produced by the combustion of an oxidizing gas and an auxiliary fuel, such as carbon disulfide, carbon selenide sulfide, or carbon thiophosgene, consisting of a hydrogen-free compound containing sulfur bonded directly to carbon. The stated reference does not

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utilize the halide-free, silicon-containing compounds employed in the instant invention.

U.S. Patent 2,239,551 ( Dalton) discloses a method of making glass by decomposing a gaseous mixture of glass forming compounds in a flame of combustible gas, said mixture being used in the formation of anhydrous oxides of silicon, aluminum, and boron. Decomposable compounds such as ethyl or methyl silicate, silicochloroform, and silicon tetrafluoride may be substituted for silicon tetrachloride; methyl borate or boron hydride may be substituted for boron fluoride, etc. The stated reference does not mention any of the halide-free, silicon-containing compounds deemed to be the essence of the instant invention.

U.S. Patent 2,326,059 (Nordberg) details a technique for making silica-rich ultra-low expansion glass by vaporizing tetrachlorides of Si and Ti into the gas stream of an oxy-gas burner, depositing the resultant mixture to make a preform, vitrifying the preform at 1500°C to make an opal glass, and firing the opal preform at a higher temperature to cause it to become transparent. Unlike the instant invention, the stated reference does not employ the use of halide-free, silicon-containing required in the present inventive process.

U.S. Patent 2,272,342 (Hyde) details a method of producing glass articles containing vitreous silica by vaporizing a hydrolyzable compound of silicon such as silicon chloride, silicochloroform, methyl silicate, ethyl silicate, silicon flouride, or mixtures thereof, using a water bath. The silicon compound vapor is hydrolyzed by water vapor in the flame of a burner and the resulting amorphous oxide is collected and subsequently sintered until a transparent glass results. The stated reference does not mention the halide-free, silicon-containing compounds forming the basis of the instant invention.

U.S. Patent No. 4,501,602 was referred to above as describing the production of particulate metal oxide soot

through the vapor phase deposition of  $\beta$ -diketonate complexes of metals from Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, and the rare earth series of the Periodic Table. Not only is no mention made of the halide-free, silicon-containing compounds required in the instant invention, but also the sole reference to a silicon-containing compounds is  $\text{SiCl}_4$ .

Also cited in the art are several patents wherein silane and modifications thereof have been used in producing high purity fused silica. For example:

10 Japanese Patent Application No. 90838-1985, entitled MANUFACTURING METHOD OF QUARTZ GLASS PREFORM FOR OPTICAL TRANSMISSION, (Okamoto et al.) discloses a method of doping quartz glass by utilizing an ester silane expressed by the general formula  $\text{R}^1_n \text{Si}(\text{OR}^2)_{4-n}$  and one or more  
15 dopants defined by the formulas  $\text{Ge}(\text{OR}^3)_3$ ,  $\text{B}(\text{OR}^3)_3$ , and  $\text{PH}_3$ , where  $\text{R}^1$  is a hydrogen atom, methyl or ethyl group;  $\text{R}^2$  is a methyl or ethyl group;  $\text{R}^3$  is an univalent hydrocarbon group; and  $n$  is an integer ranging between 0 and 4. A plethora of organometallic compounds are  
20 disclosed including methyltrimethoxysilane, dimethyldimethoxysilane, trimethylmethoxysilane, tetramethoxysilane, methyltriethoxysilane, and tetraethoxysilane. None of those compounds is utilized in our inventive method.

25 U.S. Patent 3,117,838 (Sterling) describes a method of producing very pure fused quartz or silica by the combined thermal decomposition and oxidation of silane wherein either carbon dioxide, nitrous oxide, or water vapor and silane are fed into a burner or torch jet and  
30 the flame allowed to impinge on a carbon substrate upon which silica is deposited. Unlike the instant invention, the stated reference does not employ the use of halide-free, silicon-containing compounds required in the present inventive method.

35 U.S. Patent 4,810,673 (Freeman) discloses a method of synthesizing high quality silicon oxides by chemical

vapor deposition of a source gas mixture which includes a halogenated silane component and an oxygen source, namely dichlorosilane and nitrous oxide. Unlike the instant invention, the stated reference does not employ the use of halide-free, silicon-containing compounds as a silicon-source compound.

U.S. Patent 4,242,487 (Hasegawa et al.) discloses a method of producing a heat resistant, semi-inorganic compound that is useful as a material for various heat resistant materials by reacting an organoborosiloxane compound with at least one of the group of aliphatic polyhydric alcohols, aromatic alcohols, phenols, and aromatic carboxylic acids at 250°C to 450°C in an inert atmosphere. The stated reference does not mention the halide-free, silicon-source compounds deemed to be the essence of the instant invention.

#### Brief Description of Drawings

FIGURE 1 comprises a schematic representation of the apparatus and process for forming large masses of fused silica.

FIGURES 2 and 2A comprise schematic representations of the apparatus and process for depositing silica soot on a rotating mandrel to form a porous blank or preform.

FIGURE 3 comprises a schematic representation of a heating chamber wherein the porous blank is fired in an atmosphere of helium and chlorine to full consolidation to a non-porous body.

#### Preferred Embodiments

In the preferred embodiment of the invention disclosed and claimed in Serial No. 07/568,230, octamethylcyclotetrasiloxane (OMCTS) was the halide-free siloxane compound used as the feedstock in the vapor deposition



processes utilized in making high purity fused silica for optical waveguide applications. Fused silica produced by oxidation of octamethylcyclotetrasiloxane results in the production of carbon dioxide and water as by-products.

5 In the boule process oxygen is bubbled through a  $\text{SiCl}_4$  feedstock that is maintained at a specified low temperature. The vaporous  $\text{SiCl}_4$  is entrained in oxygen, which acts as a carrier gas, transporting the vaporous  $\text{SiCl}_4$  to the reaction site. The reaction site is comprised of a number of burners that combust and oxidize the  
10 vaporous  $\text{SiCl}_4$  at a temperature greater than  $1700^\circ\text{C}$ .

#### Example 1

15 The aforementioned system is illustrated in Figure 1 wherein  $\text{SiCl}_4$  was replaced with an OMCTS feedstock 1 in a commercial furnace to produce boules of high purity fused silica. An inert gas, nitrogen, was used as the carrier gas and a bypass stream of nitrogen 2 was introduced to prevent saturation of the vaporous stream. The vaporous  
20 reactant was passed through a distribution mechanism 3 before being transported to the reaction site wherein a number of burners 4 are contained in close proximity to a furnace crown 5. These burners combusted and oxidized the vaporous reactants at a temperature greater than  $1700^\circ\text{C}$ , directing high purity metal oxide soot and heat downward  
25 through the refractory furnace crown 5 where it is immediately deposited and consolidated to a nonporous mass on a hot bait 6.

30 In the production of relatively large boules, the maximum soot collection efficiencies measured using  $\text{SiCl}_4$  as the feedstock have ranged about 60-70%. Extensive trials have indicated that the average deposition efficiency for boule process utilizing OMCTS as the source material is at least 10% higher than those processes using  
35  $\text{SiCl}_4$ . Therefore, in addition to eliminating halide

emissions, the quantity of particulate emissions is likewise reduced.

5 It is well recognized in the art that processing of the feedstock requires apparatus and transfer system capable of vaporizing the feedstock and delivering it in the vapor state. Somewhat higher temperatures are necessary due to its lower vapor pressure when compared to  $\text{SiCl}_4$ .

Example 2

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To broaden the general class of alternative non-polluting sources of silica, a number of organometallic compounds were investigated with several objectives in mind. First, we wanted to demonstrate that silica soot can, indeed, be made from the organosilicon compounds of the instant invention. Second, we wanted to determine whether the linear siloxanes would produce silica soot as has been demonstrated with the cyclosiloxanes (e.g. OMCTS). Third, we wanted to determine whether the Si-N bond of organosilicon-nitrogen compounds could be broken and replaced by a Si-O bond of higher bond strength during the combustion process. Finally, in accordance with the spirit of the instant invention, when decomposed to make high purity fused silica, the by-products of said organosilicon compounds and the consequential emissions of said organosilicon compounds must be classified as environmentally safe by the OSHA (Occupational Health and Safety Administration) and the EPA (Environmental Protection Agency).

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Experimental samples were either directly metered as liquid to a flash vaporizer, or as in one case, melted and bubbled over to the fume tube of a standard methane/oxygen ring burner. Octamethylcyclotetrasilazane, tris (trimethylsilyl) ketenimine, and octamethyltrisiloxane were obtained through commercial manufacturers and soot was produced

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from each. The soot was collected and chemically analyzed to determine the silicon, nitrogen, and oxygen content of each. The error of the wt.% O<sub>2</sub> is shown parenthetically to the last place indicated.

5

TABLE I

| Compound                               | %Nitrogen | %Oxygen | %Silicon |
|--|-----------|---------|----------|
| -----<br>octamethyltrisiloxane         | < 0.01    | 53.7(4) | 46.6     |
| 10 tris (trimethylsilyl)<br>ketenimine | < 0.01    | 53.4(4) | 46.6     |
| octamethylcyclotetrasilazane           | < 0.01    | 53.1(4) | 46.6     |

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As can be seen from Table I, the linear siloxane octamethyltrisiloxane, an organosilicon-oxygen compound, the organosilicon-nitrogen compounds tris (trimethyl) ketenimine and octamethylcyclotetrasilazane pyrolyzed/hydrolyzed to yield an amount of SiO<sub>2</sub> comparable to that produced with octamethylcyclotetrasiloxane, the most preferred polymethylcyclosiloxane described in Serial No. 07/568,230.

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The bond energy of the Si-O bond is 191.1 ± 3.2 kcal/mole and that of the Si-N bond is 105 ± 9 kcal/mole. Thus, the energy of the Si-N bond is about 86 ± 10 kcal/mole less than that of the Si-O bond. The utility of tris (trimethyl) ketenimine in yielding SiO<sub>2</sub> confirms one of the above criteria which an operable organosilicon-R compound must obey; viz., that the dissociation energy of the Si-R bond must not exceed that of the Si-O bond. That factor, i.e., the presence of a Si-N bond, explains the effectiveness of siloxasilazanes in producing high purity SiO<sub>2</sub> when subjected to a pyrolysis/hydrolysis reaction with oxygen. The reaction products will essentially track

those resulting from the pyrolysis/hydrolysis of an organosilicon-nitrogen compound.

A practical advantage which these materials have when compared to octamethylcyclotetrasiloxane is that the purity thereof is much higher. The specifically-described organosilicon compounds of the instant invention are generally free from the high levels of alkali metal and transition metal impurities found in OMCTS. OMCTS is reported to be 95% pure, while the cited organosilicon compounds of the instant invention have a reported 99% purity. The 5% level of impurities for OMCTS consists of higher molecular weight cyclosiloxanes not being totally separated by fractional distillation, and trace amounts of alkali and transition metals.

In waveguide processing, however, the requisite step of chlorine drying not only removes water, but also removes the alkali and transition metal impurities to a level < 10 ppb, the level required when producing low attenuation fiber. Thus, the effect of these alkali and transition metal impurities is neutralized in the traditional processing sequence of optical waveguide fiber.

Most of the processes being developed by industry today for the manufacture of optical waveguides employ the chemical vapor deposition (CVD) concept or a modified version thereof. In a CVD experiment, each of the component liquids is heated to a constant temperature at which enough vapor pressure is generated to produce a reasonable rate of deposition. The individual vapors are entrained in a carrier gas stream, mixed together prior to combustion to ensure homogeneous output, and then passed through a burner flame, usually a natural gas/oxygen mixture, containing excess oxygen. The vapors in the mixture are converted to their respective oxides and exit the burner orifice to form a stream of the volatile gases and finely-divided, spherical particles of soot. The soot is collected on a mandrel, <sup>[Outside Vapour Deposition]</sup> (OVD) or bait tube [Axial Vapor

Deposition (AVD)] and deposited in thin layers. The final product of soot collection, the porous preform, is then subjected to high temperature in which the preform consolidates to a nonporous monolithic glassy body.

5 In usual practice, the optical waveguide process is a three-step process. In the first stage of optical fiber fabrication, oxygen, the carrier gas, is bubbled through a liquid feedstock of  $\text{SiCl}_4$  that is maintained at a constant temperature. The resulting vaporous reactant is transported to a reaction site, such as a burner, via a carrier  
10 gas, wherein the vaporous gas streams are combusted in a burner flame fueled with natural gas and oxygen. The presence of oxygen serves to convert the vaporous reactants to their respective oxides, exiting the burner orifice to form a stream of volatile gases and finely-divided, spherical particles of soot that are deposited onto  
15 a substrate, forming a porous blank or preform of opaque, white silica soot. Water,  $\text{HCl}$ , and carbon dioxide are emitted as byproducts of this reaction.

In the second stage the blank or preform is subsequently heat treated in a helium/chlorine atmosphere to  
20 full consolidation. In the third and final stage, conventional fiber-draw technology is utilized in extracting optical waveguide fiber from the preform.

That process is illustrated in Figure 2 and is  
25 equally applicable with the materials of the present invention. Hence, as is indicated in Figure 2,  $\text{SiCl}_4$  is replaced with one of the organosilicon-R compounds as feedstock 7 in the OVD process using standard OVD equipment and conventional OVD processing techniques used in  
30 making optical waveguides. An inert gas, nitrogen, is employed as the carrier gas and a methane/oxygen mixture is employed as the burner flame fuel, whereby combustion and oxidation are induced at the reaction site 8. The resulting soot is deposited on a rotating rod 9, thus  
35 forming a preform or blank 10 of silica soot. The preform

is then heat treated in a consolidation furnace 11, in a He/Cl<sub>2</sub> atmosphere to full consolidation. Conventional fiber draw techniques are then employed in making optical waveguide fiber. No additional equipment is required, but the delivery system has to be capable of vaporizing the material and delivering it to a standard OVD burner in the vapor state.

While the principles of the instant invention have been described above in connection with specific embodiments and particular modifications thereof, it is to be clearly understood that this description is made only by way of example, and not as a limitation on the scope of the invention. Said principles may be otherwise embodied within the scope of the following claims.

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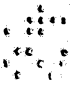
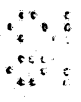
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THE CLAIMS DEFINING THE INVENTION ARE AS FOLLOWS:

1. A method for making a virtually non-porous body of high purity fused silica glass which includes the steps of:

5 (a) producing a gas stream of a halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$ ;

10 (b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $\text{SiO}_2$ ;

(c) depositing said amorphous particles onto a support; and

15 (d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a virtually nonporous body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

20 (1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than  $350^\circ\text{C}$ ; and

25 (3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards;

wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

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2. A method according to claim 1 wherein said organosilicon-oxygen compound is a linear siloxane.

35 3. A method according to claim 2 wherein said linear siloxane is octamethyltrisiloxane.



4. A method according to any one of claims 1 to 3 wherein said organosilicon-nitrogen compound is selected from the group consisting of an aminosilane, a linear silazane, and a cyclosilazane.

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5. A method according to claim 4 wherein said aminosilane is tris (trimethylsilyl) ketenimine, said linear silazane is nonamethyltrisilazane and said cyclosilazane is octamethylcyclotetrasilazane.

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6. A method according to any one of claims 1 to 5 wherein said siloxasilazane is hexamethylcyclotrisiloxazane.

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7. A method according to any one of claims 1 to 6 wherein said gas stream is comprised of an inert gas.

8. A method according to claim 7 wherein said inert gas is nitrogen.

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9. A method for making a non-porous body of high purity silicon doped with  $P_2O_5$  and/or at least one metal oxide selected from the groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table including the steps of:

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(a) producing a gas stream containing a vaporizable, halide-free, silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $SiO_2$  and a compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

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(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused





SiO<sub>2</sub> doped with P<sub>2</sub>O<sub>5</sub> and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

5 (c) depositing said amorphous particles onto a support; and

(d) either substantially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a non-porous body;  
10 wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than 350°C;  
15 and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said  
20 organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

25 10. A method according to claim 9 wherein said organosilicon-oxygen compound is a linear siloxane.

11. A method according to claim 10 wherein said linear siloxane is octamethyltrisiloxane.  
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12. A method according to any one of claims 9 to 11 wherein said organosilicon-nitrogen compound is selected from the group consisting of an aminosilane, a silazane, and a cyclosilazane.  
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13. A method according to claim 12 wherein said aminosilane is tris (trimethylsilyl) ketenimine, said linear



silazane is nonamethyltrisilazane, and said cyclosilazane is octamethylcyclotetrasilazane.

5 14. A method according to any one of claims 9 to 13 wherein said siloxasilazane is hexamethylcyclotrisiloxazane.

10 15. A method according to any one of claims 9 to 14 wherein said gas stream is comprised of an inert gas.

16. A method according to claim 15 wherein said inert gas is nitrogen.

15 17. A method according to any one of claims 9 to 16 wherein said vaporizable compound capable of being converted to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table is a halide-containing compound.

20 18. A method according to any one of claims 9 to 17 wherein said vaporizable compound capable of being converted to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table is a halide-free compound.

25 19. A method for making optical waveguide fibers of high purity fused silica through the outside vapor deposition process including the steps of:

30 (a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $SiO_2$ ;

35 (b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $SiO_2$ ;



(c) depositing said amorphous particles onto a mandrel;

(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; and

5 (e) drawing optical waveguide fiber from said body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

10 (2) a boiling point no higher than 350°C; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

20 20. A method according to claim 19 wherein said organosilicon-oxygen compound is a linear siloxane.

25 21. A method according to claim 20 wherein said linear siloxane is octamethyltrisiloxane.

30 22. A method according to any one of claims 19 to 21 wherein said organosilicon-nitrogen compound is selected from the group consisting of an aminosilane, a silazane, and a cyclosilazane.

35 23. A method according to claim 22 wherein said aminosilane is tris (trimethylsilyl) ketenimine, said linear silazane is nonamethyltrisilazane, and said cyclosilazane is octamethylcyclotetrasilazane.



24. A method according to any one of claims 19 to 23 wherein said siloxasilazane is hexamethylcyclotrisiloxazane.

5 25. A method according to any one of claims 19 to 24 wherein said gas stream is comprised of an inert gas.

26. A method according to claim 25 wherein said gas is nitrogen.

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27. A method for making optical waveguide fibers of high purity fused silica doped with  $P_2O_5$  and/or at least one metal oxide selected from the groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table through the outside vapor deposition process including the steps of:

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(a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $SiO_2$  and a compound in vapor form capable of being converted through thermal decomposition with through oxidation or flame hydrolysis to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

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25

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $SiO_2$  doped with  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table;

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(c) depositing said amorphous particles onto a mandrel;

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(d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; and

(e) drawing optical waveguide fiber from said body; wherein a halide-free, organosilicon-R compound in



vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

(2) a boiling point no higher than 350°C;

5 and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside SiO<sub>2</sub> which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said  
10 organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

15 28. A method according to claim 27 wherein said organosilicon-oxygen compound is a linear siloxane.

20 29. A method according to claim 28 wherein said linear siloxane is octamethyltrisiloxane.

30 30. A method according to any one of claims 27 to 29 wherein said organosilicon-nitrogen compound is selected from the group consisting of an aminosilane, a silazane, and a cyclosilazane.

25 31. A method according to claim 30 wherein said aminosilane is tris (trimethylsilyl) ketenimine, said linear silazane is nonamethyltrisilazane, and said cyclosilazane is octamethylcyclotetrasilazane.

30 32. A method according to any one of claims 27 to 31 wherein said siloxasilazane is hexamethylcyclotrisiloxazane.

35 33. A method according to any one claims 27 to 32 wherein said gas stream is comprised of an inert gas.



34. A method according to claim 33 wherein said inert gas is nitrogen.

5 35. A method according to any one of claims 27 to 34 wherein said compound in vapor form capable of being converted to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VA, and the rare earth series of the Periodic Table is a halide-containing compound.

10 36. A method according to any one of claims 27 to 34 wherein said vaporizable compound capable of being converted to  $P_2O_5$  and/or at least one metal oxide selected from the Groups IA, IB, IIA, IIB, IIIA, IIIB, 15 IVA, IVB, VA, and the rare earth series of the Periodic Table is a halide-free compound.

37. A method for making high purity fused silica including the steps of:

20 (a) producing a gas stream containing a silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $SiO_2$ ;

25 (b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $SiO_2$ ;

(c) depositing said amorphous particles onto a mandrel; and

30 (d) consolidating said deposit of amorphous particles into a non-porous, transparent glass body; wherein a halide-free, organosilicon-R compound in vapor form having the following properties is used:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

35 (2) a boiling point no higher than  $350^{\circ}C$ ;  
and



(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards; wherein said organosilicon-R compound is selected from the group consisting of organosilicon-oxygen compounds, organosilicon-nitrogen compounds, siloxasilazanes, and mixtures thereof.

5

10 38. A method according to claim 37 wherein said organosilicon-oxygen compound is a linear siloxane.

39. A method according to claim 38 wherein said linear siloxane is octamethyltrisiloxane.

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40. A method according to any one of claims 37 to 39 wherein said organosilicon-nitrogen compound is selected from the group consisting of an aminosilane, and a cyclosilazane.

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41. A method according to claim 40 wherein said aminosilane is tris (trimethylsilyl) ketenimine, said linear silazane is nonamethyltrisilazane, and said cyclosilazane is octamethylcyclotetrasilazane.

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42. A method according to any one of claims 37 to 41 wherein said siloxasilazane is hexamethylcyclotrisiloxazane.

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43. A method according to any one of claims 37 to 42 wherein said gas stream is comprised of an inert gas.

44. A method according to claim 43 wherein said inert gas is nitrogen.

35



45. A method of making high purity silica, substantially as herein described with reference to any one of the embodiments shown in the accompanying drawings.

5 46. A method of making high purity silica, substantially as herein described with reference to any one of the Examples.

10 DATED : 24 October 1994

PHILLIPS ORMONDE & FITZPATRICK  
Attorneys for:  
CORNING INCORPORATED

15 *David B Fitzpatrick*

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Abstract of the Disclosure

This invention relates to the production of high purity fused silica glass through oxidation and/or flame hydrolysis of a halide-free, organosilicon-R compound in vapor form having the following properties:

(a) producing a gas stream of a halide-free silicon-containing compound in vapor form capable of being converted through thermal decomposition with oxidation or flame hydrolysis to  $\text{SiO}_2$ ;

(b) passing said gas stream into the flame of a combustion burner to form amorphous particles of fused  $\text{SiO}_2$ ;

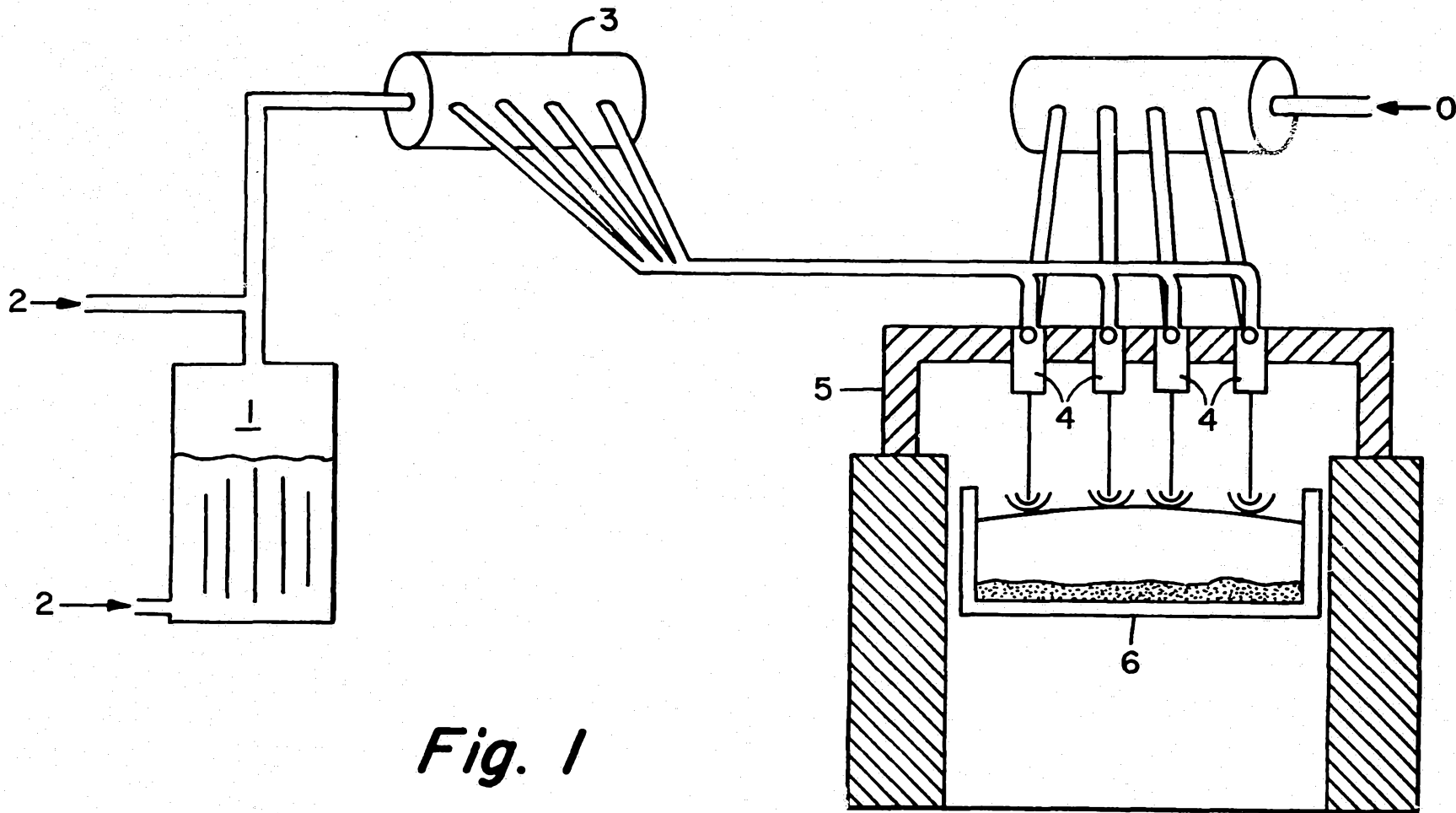
(c) depositing said amorphous particles onto a support; and

(d) either essentially simultaneously with said deposition or subsequently thereto consolidating said deposit of amorphous particles into a virtually nonporous body; the improvement comprising utilizing a halide-free, organosilicon-R compound in vapor form having the following properties:

(1) a Si-R bond dissociation energy that is no higher than the dissociation energy of the Si-O bond;

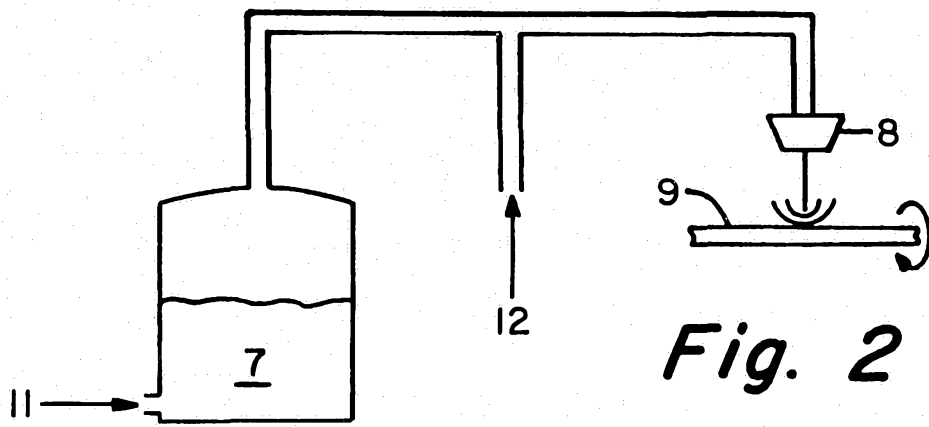
(2) a boiling point no higher than  $350^\circ\text{C}$ ; and

(3) which, upon pyrolysis and/or hydrolysis, will produce decomposition products beside  $\text{SiO}_2$  which are deemed to be environmentally safe or the emissions are below acceptable governmental standards.

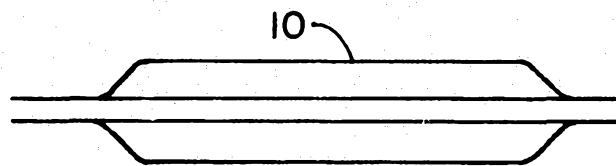


*Fig. 1*

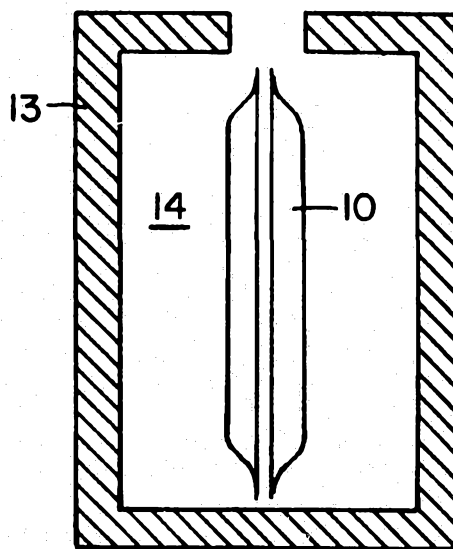
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**Fig. 2**



**Fig. 2a**



**Fig. 3**